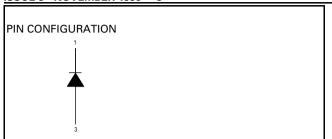
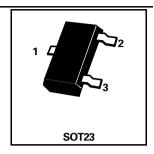
SOT23 SILICON PLANAR VOLTAGE REGULATOR DIODES

BZX84 SERIES C2V7 to C47

ISSUE 3 - NOVEMBER 1995 O





ABSOLUTE MAXIMUM RATINGS (as per Electron Coding Sytem).

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PARAMETER	SYMBOL	VALUE	UNIT
Voltage Range	V _Z	2.7 to 47	V
Nominal Tolerance	С	±5	%
Maximum Forward Current	I _F	250	mA
Power Dissipation at T _{amb} =25°C	P _{tot}	330	mW
Operating and Storage Temperature Range	T _j :T _{stg}	-55 to +150	°C

ELECTRICAL CHARACTERISTICS (at T_{amb} = 25°C).

Туре	Zener Voltage V _Z at I _Z =5mA V			Differential Resistance r _Z at I _Z =5mA Ω	Temperature Coefficient S _Z at I _Z =5mA mV/°C		Reverse Current I _R at V _R μΑ V	
BZX84:	Nom.	Min.	Max.	Max.	Min	Max	Max	Max
C2V7	2.7	2.5	2.9	100	-3.5	0	20	1
C3V0	3.0	2.8	3.2	100	-3.5	0	10	1
C3V3	3.3	3.1	3.5	100	-3.5	0	5	1
C3V6	3.6	3.4	3.8	100	-3.5	0	5	1
C3V9	3.9	3.7	4.1	100	-3.5	0	3	1
C4V3	4.3	4.0	4.6	90	-3.5	0	3	1
C4V7	4.7	4.4	5.0	80	-3.5	0.2	3	2
C5V1	5.1	4.8	5.4	60	-2.7	1.2	2	2
C5V6	5.6	5.2	6.0	40	-2.0	2.5	1	2
C6V2	6.2	5.8	6.6	10	0.4	3.7	3	4
C6V8	6.8	6.4	7.2	15	1.2	4.5	2	4
C7V5	7.5	7.0	7.9	15	2.5	5.3	1	5
C8V2	8.2	7.7	8.7	15	3.2	6.2	0.7	5

BZX84 SERIES C2V7 to C47

ELECTRICAL CHARACTERISTICS (at T_{amb} = 25°C).

Туре	Zener Voltage (V) V _Z at I _Z =1mA	Differential Resistance (Ω) r _Z at I _Z =1mA	Partmarking	
BZX84:	Min.	Max.		
C2V7	1.9	600	W4	
C3V0	2.1	600	W5	
C3V3	2.4	600	W6	
C3V6	2.7	600	W7	
C3V9	3.0	600	W8	
C4V3	3.3	600	W9	
C4V7	3.7	500	Z1	
C5V1	4.2	480	Z2	
C5V6	4.8	400	Z3	
C6V2	5.6	150	Z4	
C6V8	6.3	80	Z5	
C7V5	6.9	80	Z6	
C8V2	7.6	80	Z7	
C9V1	8.4	100	Z8	
C10	9.3	150	Z9	
C11	10.2	150	Y1	
C12	11.2	150	Y2	
C13	12.3	170	Y3	
C13V6	12.3	170	Y36	
C15	13.7	200	Y4	
C16	15.2	200	Y5	
C18	16.7	225	Y6	
C20	18.7	225	Y7	
C22	20.7	250	Y8	
C24	22.7	250	Y9	
	V _z at I _Z =0.5mA	r _z at I _Z =0.5mA		
C27	25.0	300	X1	
C30	27.8	300	X2	
C33	30.8	325	Х3	
C36	33.8	350	X4	
C39	36.7	350	X5	
C43	39.7	375	X6	
C47	43.7	375	X7	



ELECTRICAL CHARACTERISTICS (at T_{amb} = 25°C).

Туре		Zener Voltage V _Z at I _Z =2mA VOLTS		Differential Resistance r_Z at I_Z =2mA	Temperature Coefficient S _Z at I _Z =2mA mV/°C		Reverse Current I _R at V _R μΑ V	
BZX84:	Nom.	Min.	Max.	Max.	Min	Max	Max	Max
C10	10	9.4	10.6	20	4.5	8.0	0.2	7
C11	11	10.4	11.6	20	5.4	9.0	0.1	8
C12	12	11.4	12.7	25	6.0	10.0	0.1	8
C13	13	12.4	14.1	30	7.0	11.0	0.1	9
C13V6	13.6	12.9	14.3	30	7.0	11.0	0.1	9
C15	15	13.8	15.6	30	9.2	13.0	0.05	10
C16	16	15.3	17.1	40	10.4	14.0	0.05	11
C18	18	16.8	19.1	45	12.4	16.0	0.05	13
C20	20	18.8	21.2	55	14.4	18.0	0.05	14
C22	22	20.8	23.3	55	16.4	20.0	0.05	15
C24	24	22.8	25.6	70	18.4	22.0	0.05	17
C27	27	25.1	28.9	80	21.4	25.3	0.05	19
C30	30	28.0	32.0	80	24.4	29.4	0.05	21
C33	33	31.0	35.0	80	27.4	33.4	0.05	23
C36	36	34.0	38.0	90	30.4	37.4	0.05	25
C39	39	37.0	41.0	130	33.4	41.2	0.05	27
C43	43	40.0	46.0	150	37.6	46.6	0.05	30
C47	47	44.0	50.0	170	42.0	51.8	0.05	33